

TOSHIBA Zener Diode Silicon Epitaxial Planar Type

CSLZ Series

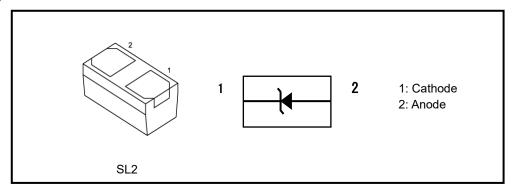
Applications

Voltage surge protection

Features

Small package

Packaging and Internal Circuit



Absolute Maximum Ratings 1 (Note) (Unless otherwise specified, Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Power dissipation	P _D *1	150	mW
	P _D *2	400	mW
Junction temperature	Tj	150	°C
Storage temperature	T _{stg}	-55 to 150	°C

Absolute Maximum Ratings 2 (Note) (Unless otherwise specified, Ta = 25°C)

Type No.	Electrostatic discharge voltage *3		Peak pulse	Peak pulse	Type No.	Electrostatic discharge voltage *3		Peak pulse	Peak pulse
	Contact	Air	power *4	current *4		Contact	Air	power *4	current*4
	VESD(kV)		Ppk(W)	IPP(A)		VESD(kV)		Ppk(W)	IPP(A)
CSLZ5V6	± 30		32	2.5	CSLZ12V	± 20		72	2.5
CSLZ6V2	± 30		37	2.5	CSLZ16V	± 12		87	2.5
CSLZ6V8	± 30		40	2.5	CSLZ20V	± 12		105	2.5
CSLZ8V2	± 30		55	2.5	CSLZ24V	± 10		117	2.5
CSLZ10V	± 30		60	2.5	CSLZ30V	±	8	145	2.5

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- *1: Mounted on a glass epoxy circuit board of 20 mm × 20 mm, pad dimensions of 4 mm × 4 mm.
- *2: Mounted on a glass epoxy circuit board of 25.4 mm × 25.4 mm × 1.6 mmt, Cu pad: 645 mm²
- *3: according to IEC61000-4-2
- *4: according to IEC61000-4-5, tp = $8 / 20 \mu s$

Start of commercial production 2022-04



Electrical Characteristics (Unless otherwise specified, Ta = 25 °C)

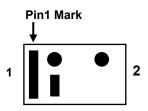
Type No.	Zener Voltage			Dynamic Impedance		Dynamic resistance	Clamp voltage	Total capacitance	Reverse Current		
	V _Z (V) Test Current		$Z_{Z}(\Omega)$	Test Current	$R_{DYN}(\Omega)^{*1}$	V _C (V) *1*2	C _t (pF) *3	I _R (μA)	Test Voltage		
	Min	Тур.	Max	Iz (mA)	Max	Iz (mA)	Тур.	Тур.	Тур.	Max	V _R (V)
CSLZ5V6	5.3	5.6	6.0	5	30	5	0.25	9	35	1.0	3.5
CSLZ6V2	5.8	6.2	6.6	5	30	5	0.38	10.5	30	2.5	5.0
CSLZ6V8	6.4	6.8	7.2	5	30	5	0.5	14.5	25	0.5	5.0
CSLZ8V2	7.7	8.2	8.7	5	30	5	0.62	17	18	0.5	6.5
CSLZ10V	9.4	10	10.6	5	30	5	0.5	18	16	0.5	8.0
CSLZ12V	11.4	12	12.6	5	30	5	1.5	28	13	0.5	9
CSLZ16V	15.3	16	17.1	5	35	5	1.7	30	10.5	0.5	12
CSLZ20V	18.8	20	21.2	5	50	5	2.5	30	9.5	0.5	15
CSLZ24V	22.8	24	25.6	5	70	5	1.5	34	8.5	0.5	19
CSLZ30V	28	30	31.5	2	150	2	4	51	7.5	0.5	23

^{*1:} TLP parameters: $Z_0 = 50 \Omega$, $t_p = 100$ ns, $t_r = 300$ ps, averaging window: $t_1 = 30$ ns to $t_2 = 60$ ns, extraction of dynamic resistance using least squares fit of TLP characteristics between ITLP1 = 8 A and ITLP2 = 16 A.

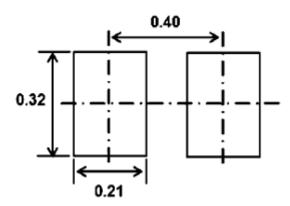
Marking List

Type No.	Marking	Type No.	Marking
CSLZ5V6		CSLZ12V	
CSLZ6V2	1	CSLZ16V	1.*.
CSLZ6V8	li**	CSLZ20V	
CSLZ8V2		CSLZ24V	
CSLZ10V	1	CSLZ30V	

Marking (CSLZ5V6)



Land Pattern Dimensions (for reference only) (Unit: mm)

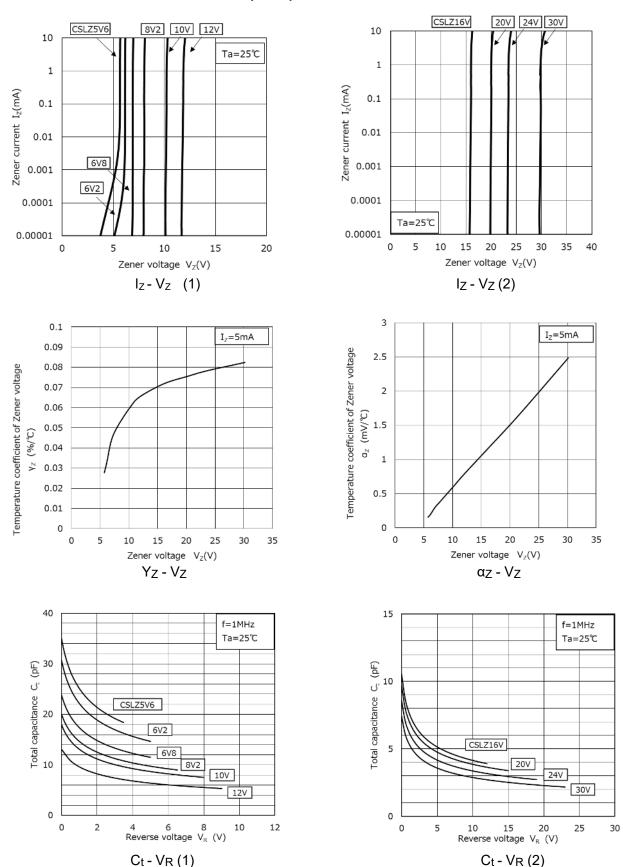


^{*2:} ITLP = 8 A

^{*3:} VR = 0 V, f = 1 MHz



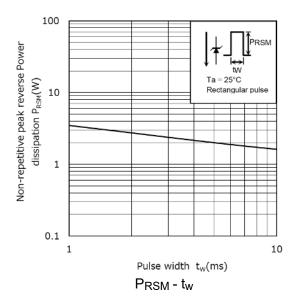
CSLZ series Characteristics Curves (Note)

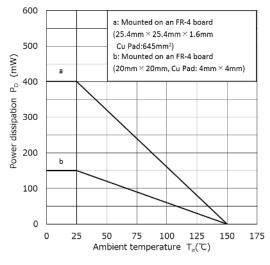


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

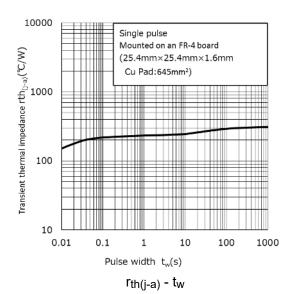


CSLZ series Characteristics Curves (Note)





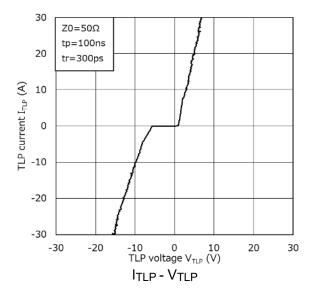


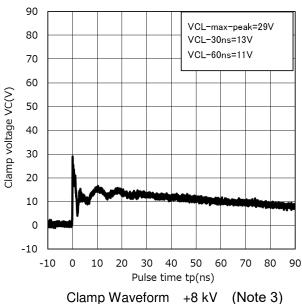


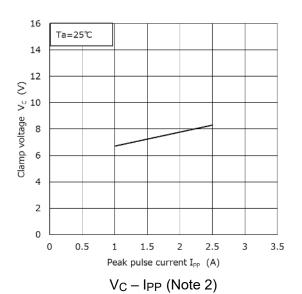
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

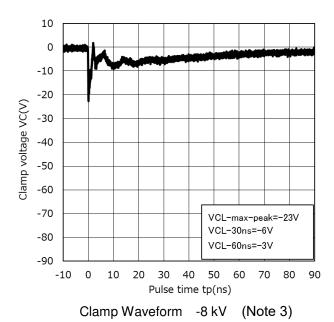


CSLZ5V6 Characteristics Curves (Note 1)





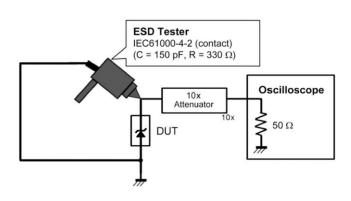




(Note 2) Peak Pulse Current (V_C - I_{PP})

1 100% 90% 20µs 10% 0% 1 + T + 8µs +

Based on IEC61000-4-5 8/20 µs pulse..

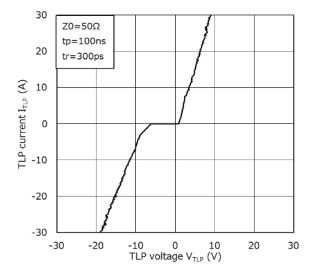


Based on IEC61000-4-2 (Contact)

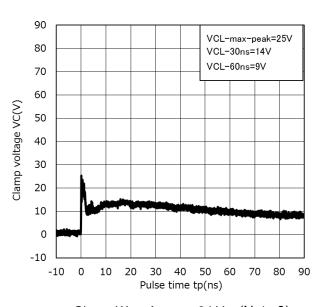
Note 1: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



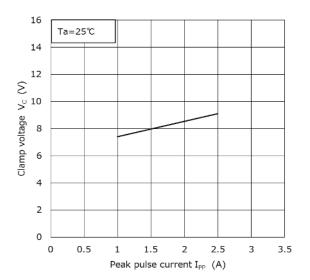
CSLZ6V2 Characteristics Curves (Note 1)



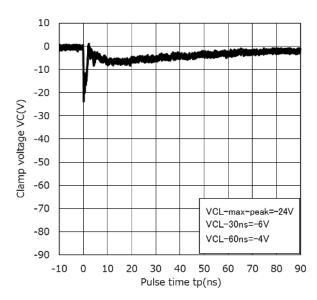




Clamp Waveform +8 kV (Note 3)

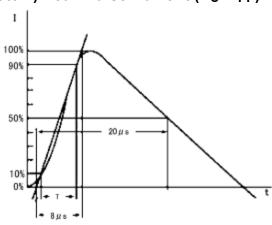


V_C - I_{PP} (Note 2)

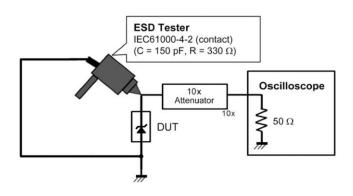


Clamp Waveform -8 kV (Note 3)

(Note 2) Peak Pulse Current (V_C - I_{PP})



Based on IEC61000-4-5 8/20 µs pulse.

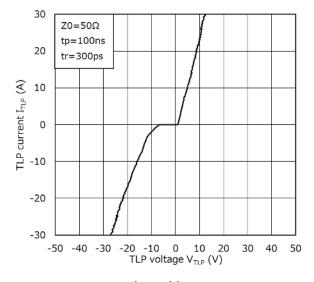


Based on IEC61000-4-2 (Contact)

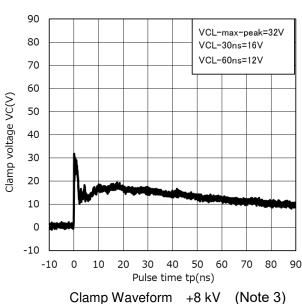
Note 1: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

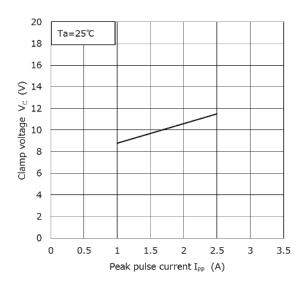


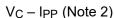
CSLZ6V8 Characteristics Curves (Note 1)

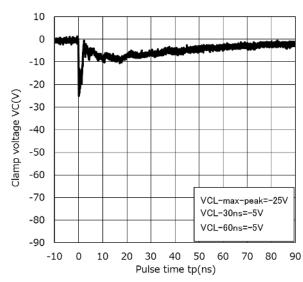






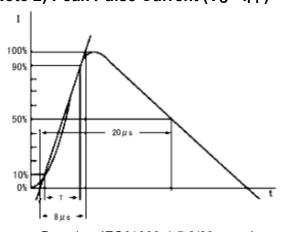




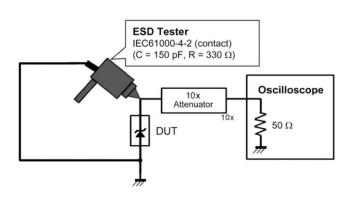


Clamp Waveform -8 kV (Note 3)

(Note 2) Peak Pulse Current (V_C - I_{PP})



Based on IEC61000-4-5 $8/20~\mu s$ pulse.

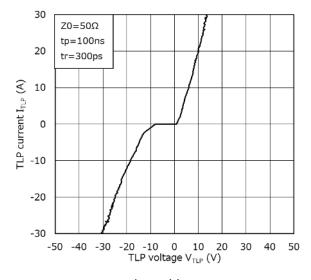


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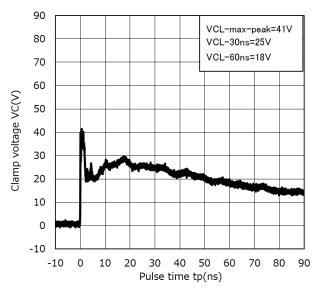
Note 1: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



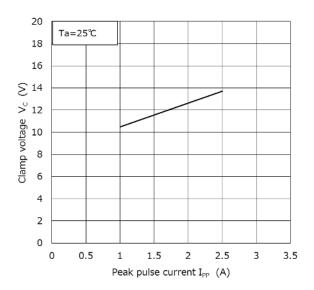
CSLZ8V2 Characteristics Curves (Note 1)



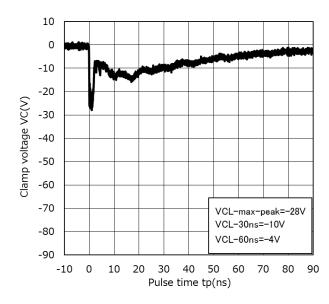




Clamp Waveform +8 kV (Note 3)

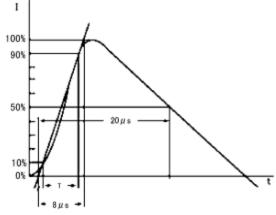


V_C - I_{PP} (Note 2)

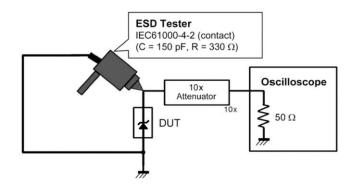


Clamp Waveform -8 kV (Note 3)

(Note 2) Peak Pulse Current (V_C - I_{PP})



Based on IEC61000-4-5 8/20 µs pulse.

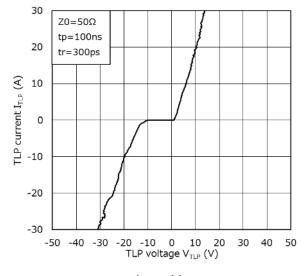


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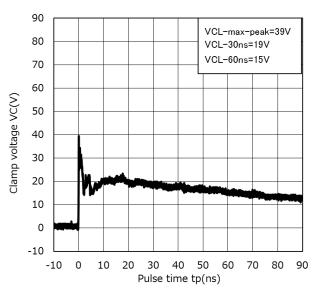
Note 1: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



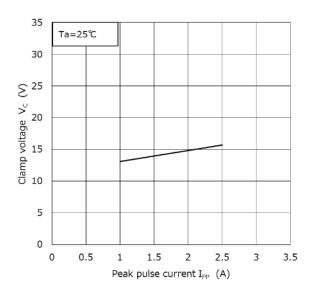
CSLZ10V Characteristics Curves (Note 1)



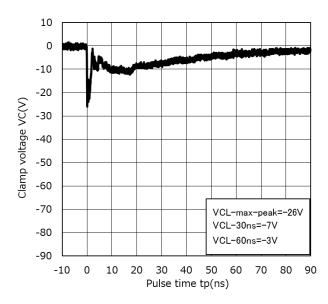




Clamp Waveform +8 kV (Note 3)



Vc - Ipp (Note 2)

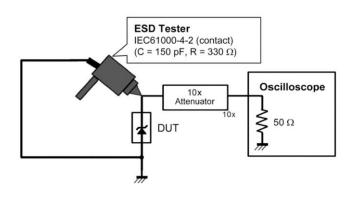


Clamp Waveform -8 kV (Note 3)

(Note 2) Peak Pulse Current (V_C - I_{PP})

100% 90% 50% 10% 0%

Based on IEC61000-4-5 8/20 µs pulse.

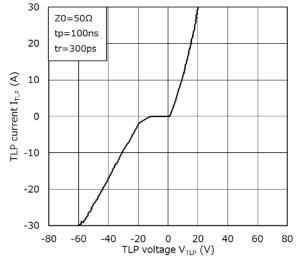


Based on IEC61000-4-2 (Contact)

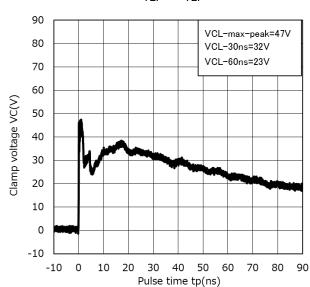
Note 1: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



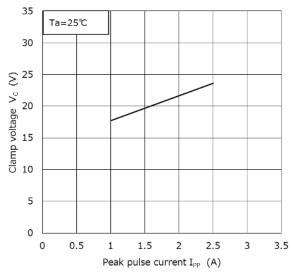
CSLZ12V Characteristics Curves (Note 1)



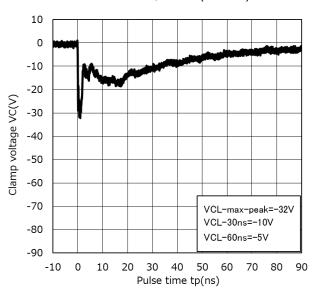




Clamp Waveform +8 kV (Note 3)

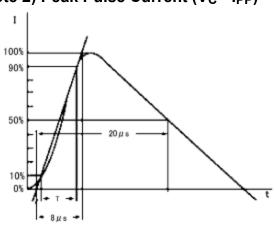


V_C – I_{PP} (Note 2)

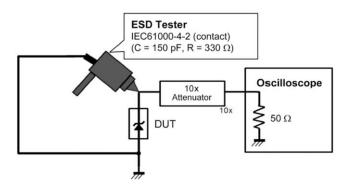


Clamp Waveform -8 kV (Note 3)

(Note 2) Peak Pulse Current (V_C - I_{PP})



Based on IEC61000-4-5 8/20 µs pulse.

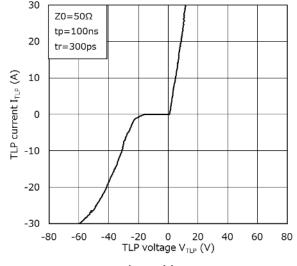


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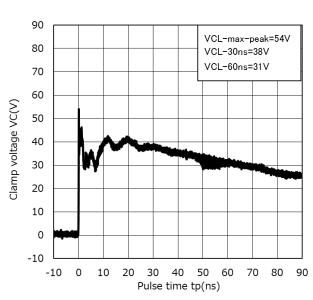
Note 1: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



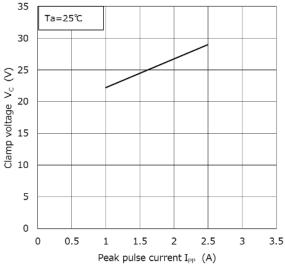
CSLZ16V Characteristics Curves (Note 1)



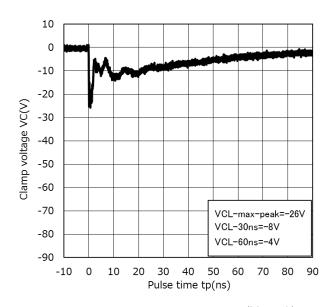




Clamp Waveform +8 kV (Note 3)

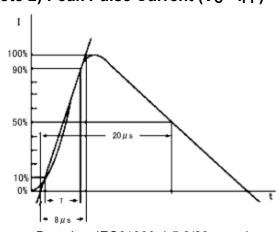


V_C - I_{PP} (Note 2)

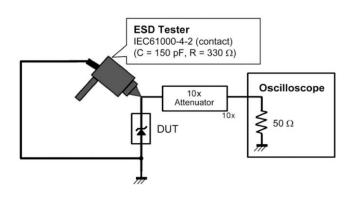


Clamp Waveform -8 kV (Note 3)

(Note 2) Peak Pulse Current (V_C - I_{PP})



Based on IEC61000-4-5 8/20 μs pulse.

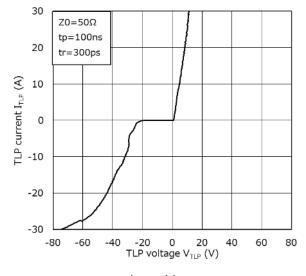


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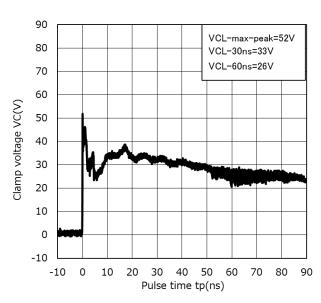
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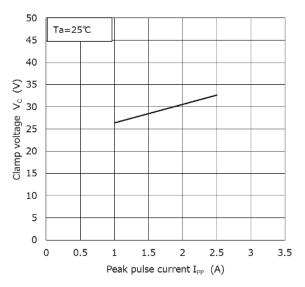
CSLZ20V Characteristics Curves (Note 1)



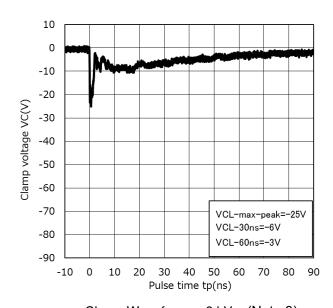




Clamp Waveform +8 kV (Note 3)



V_C - I_{PP} (Note 2)

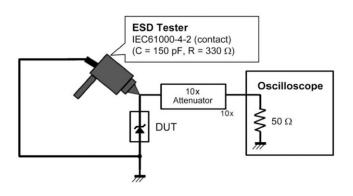


Clamp Waveform -8 kV (Note 3)

(Note 2) Peak Pulse Current (V_C - I_{PP})

100% 90% 50% 10% 0%

Based on IEC61000-4-5 8/20 µs pulse.

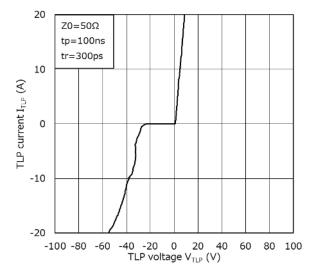


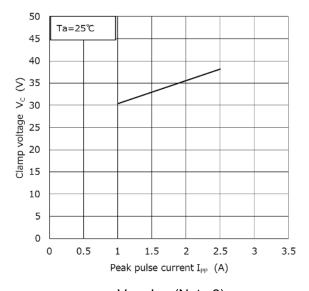
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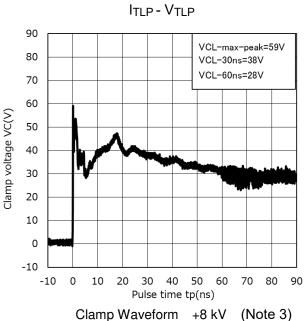
Note 1: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

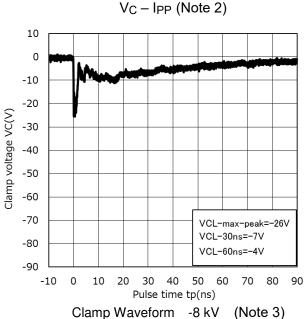


CSLZ24V Characteristics Curves (Note 1)

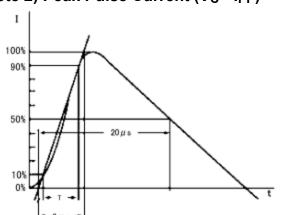




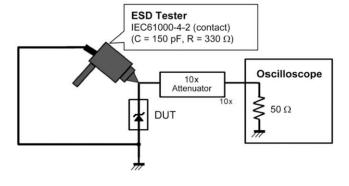




(Note 2) Peak Pulse Current (V_C - I_{PP})



(Note 3) Clamp waveform measurement circuit



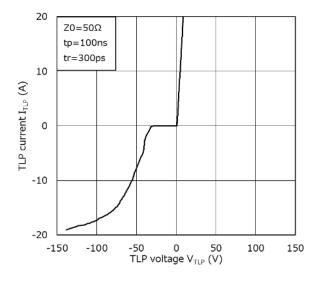
Based on IEC61000-4-5 8/20 µs pulse.

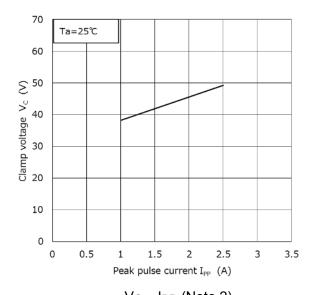
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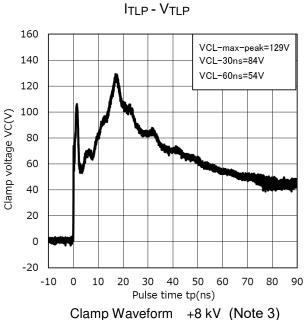
Note 1: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

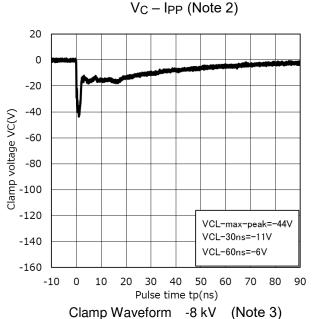


CSLZ30V Characteristics Curves (Note 1)

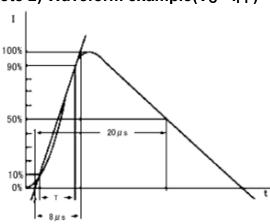




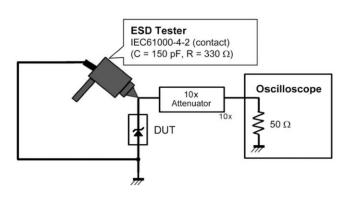




(Note 2) Waveform example(V_C - I_{PP})



(Note 3) Clamp waveform measurement circuit



Based on IEC61000-4-5 8/20 μs pulse.

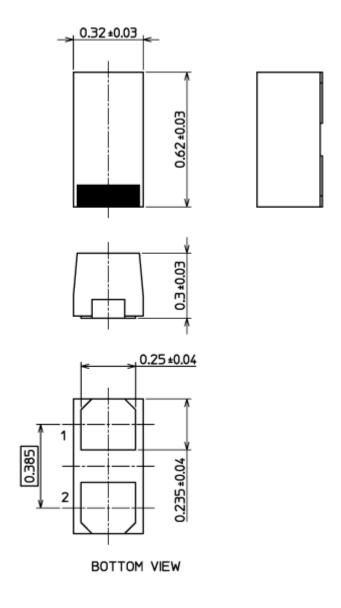
Based on IEC61000-4-2 (Contact)

Note 1: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 0.2 mg (typ.)



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